NSN 5961-01-333-7713

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Inclosure Material:

Ceramic and metal

Overall Length:

Between 0.970 inches and 0.990 inches

Overall Height:

0.310 inches

Overall Width:

0.810 inches

End Application:

5865-01-219-2097 jamming system, communications, general utility

Mounting Facility Quantity:

2

Internal Configuration:

Field effect

Mounting Method:

Unthreaded hole

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

40.0 gate to source voltage and 80.0 drain to source voltage and 80.0 drain to gate voltage

Current Rating Per Characteristic:

6.00 amperes drain current

Power Rating Per Characteristic:

120.0 watts total device dissipation

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Terminal Type And Quantity:

3 ribbon

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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